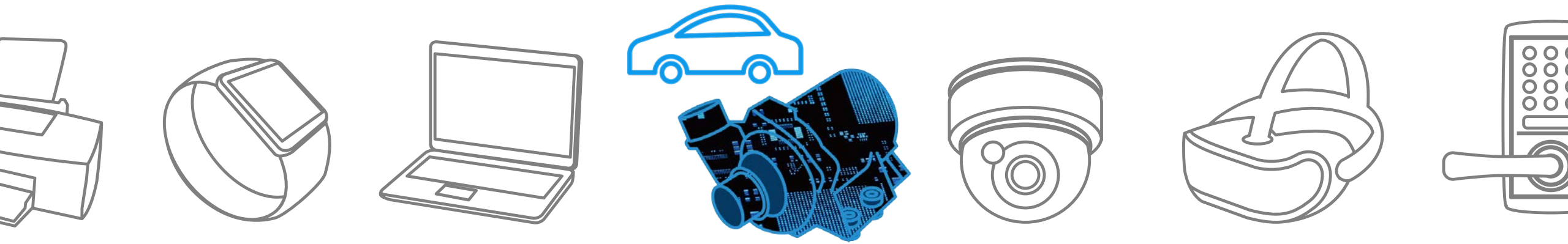
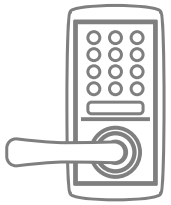
TOSHIBA

R20

Automotive Electric Water Pump

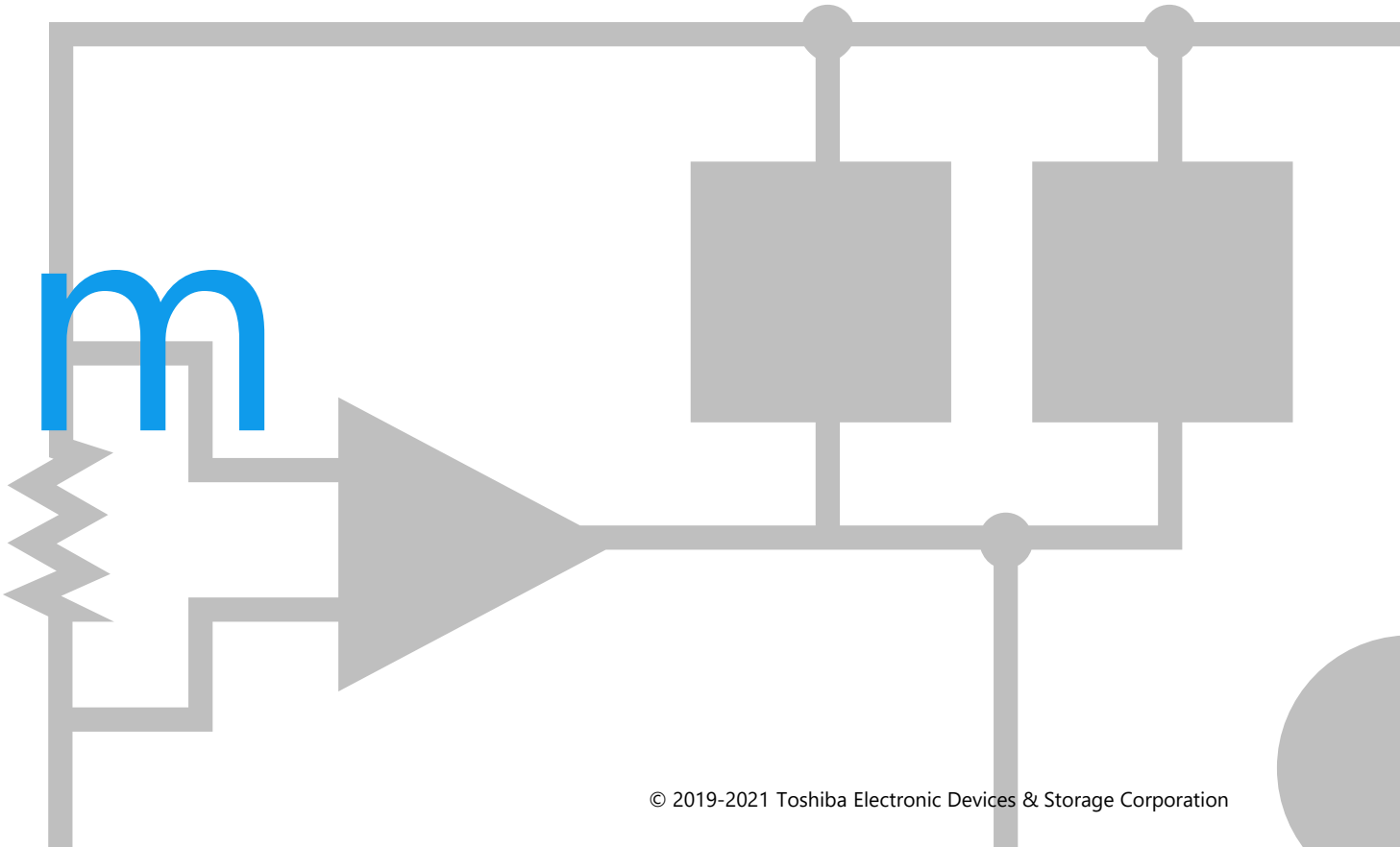
Solution Proposal by Toshiba



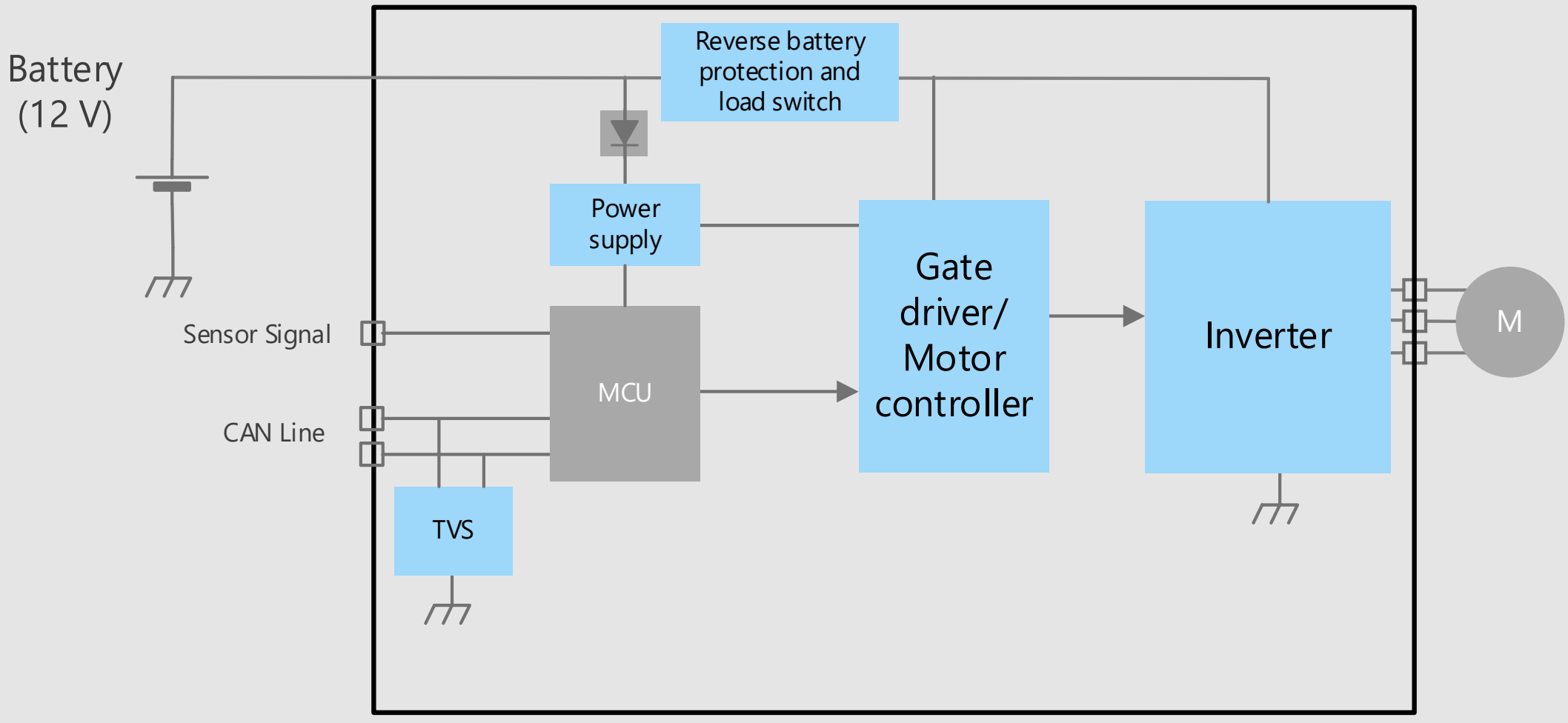


Toshiba Electronic Devices & Storage Corporation provides comprehensive device solutions to customers developing new products by applying its thorough understanding of the systems acquired through the analysis of basic product designs.

Block Diagram

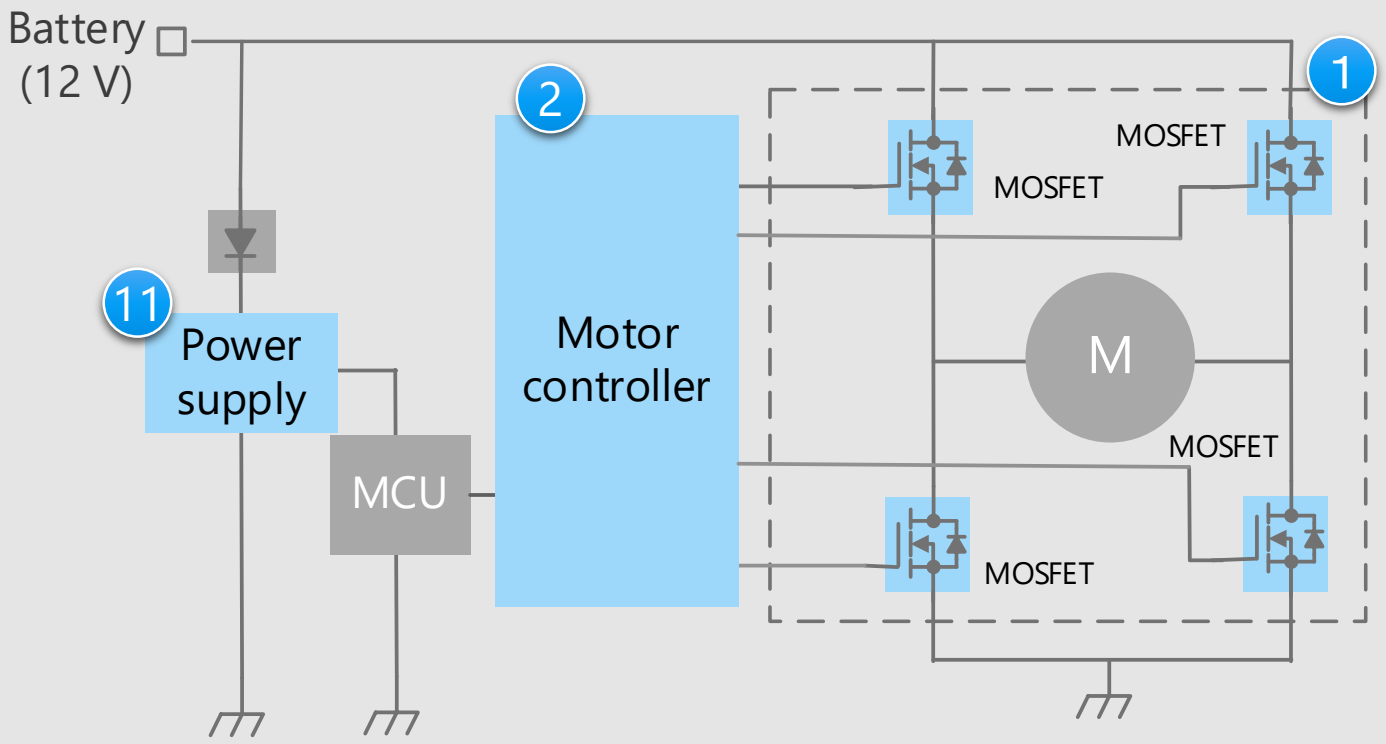


Electric Water Pump　Overall block diagram



Electric Water Pump　Detail of driving circuit fo brushed DC motor

Driving circuit for brushed DC motor (N-ch type)



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

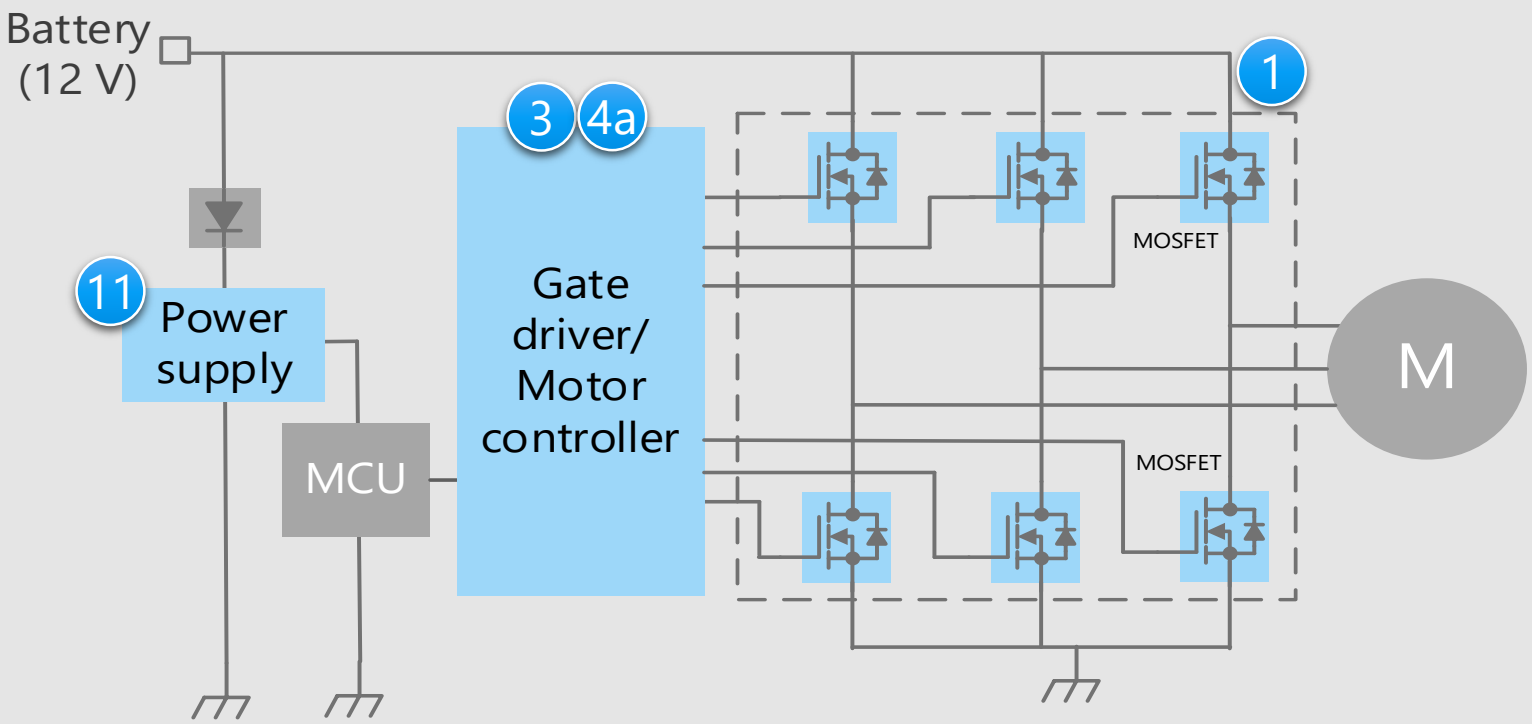
- It is necessary to select the product with the suitable voltage and current ratings for each application.
- It is necessary to select a gate driver according to the characteristics of the switching device to be driven.
- A small surface mount package is suitable for realizing miniaturization of the ECU.

Proposals from Toshiba

- **Low on-resistance contributes low power consumption of the system**
  U-MOS Series 40 V N-ch MOSFET　1
- **H-bridge pre driver compliant with automotive functional safety standard**
  Brushed DC motor pre driver　2
- **Voltage regulator with low current consumption**
  Power supply IC (for MCU)　11

Electric Water Pump　Detail of driving circuit for brushless DC motor (1)

Driving circuit for brushless DC motor (N-ch type)



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

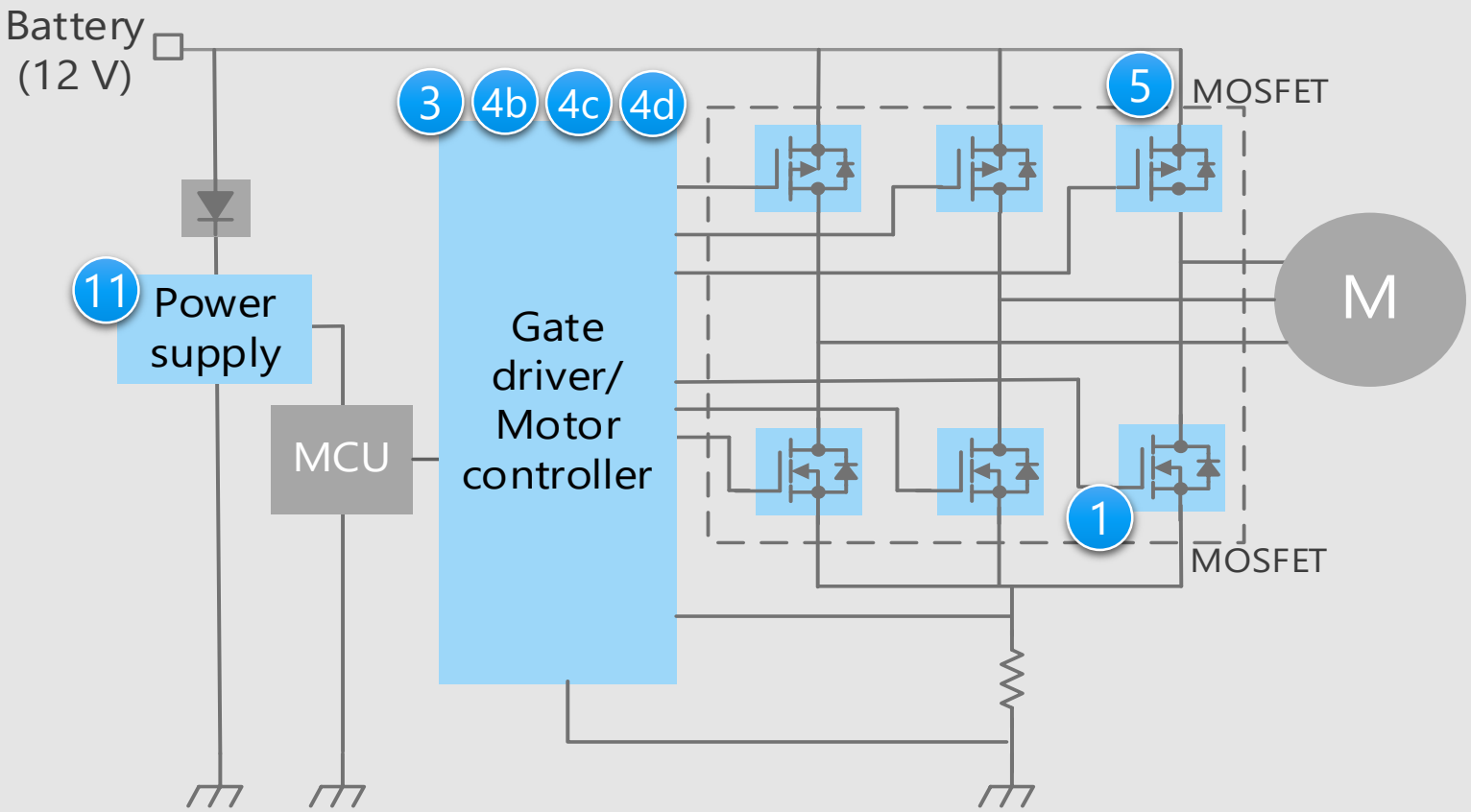
- It is necessary to select the product with the suitable voltage and current ratings for each application.
- It is necessary to select a gate driver according to the characteristics of the switching device to be driven.
- A small surface mount package is suitable for realizing miniaturization of the ECU.

Proposals from Toshiba

- **Low on-resistance contributes low power consumption of the system**
  U-MOS Series 40 V N-ch MOSFET　1
- **Gate driver with protection diagnostic function**
  Gate driver (for motor)　3
- **Full bridge pre driver compliant with automotive functional safety standard**
  Brushless DC motor pre driver　4a
- **Voltage regulator with low current consumption**
  Power supply IC (for MCU)　11

Electric Water Pump　Detail of driving circuit for brushless DC motor (2)

Driving circuit for brushless DC motor (N-ch/P-ch type)



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

- It is necessary to select the product with the suitable voltage and current ratings for each application.
- It is necessary to select a gate driver according to the characteristics of the switching device to be driven.
- A small surface mount package is suitable for realizing miniaturization of the ECU.

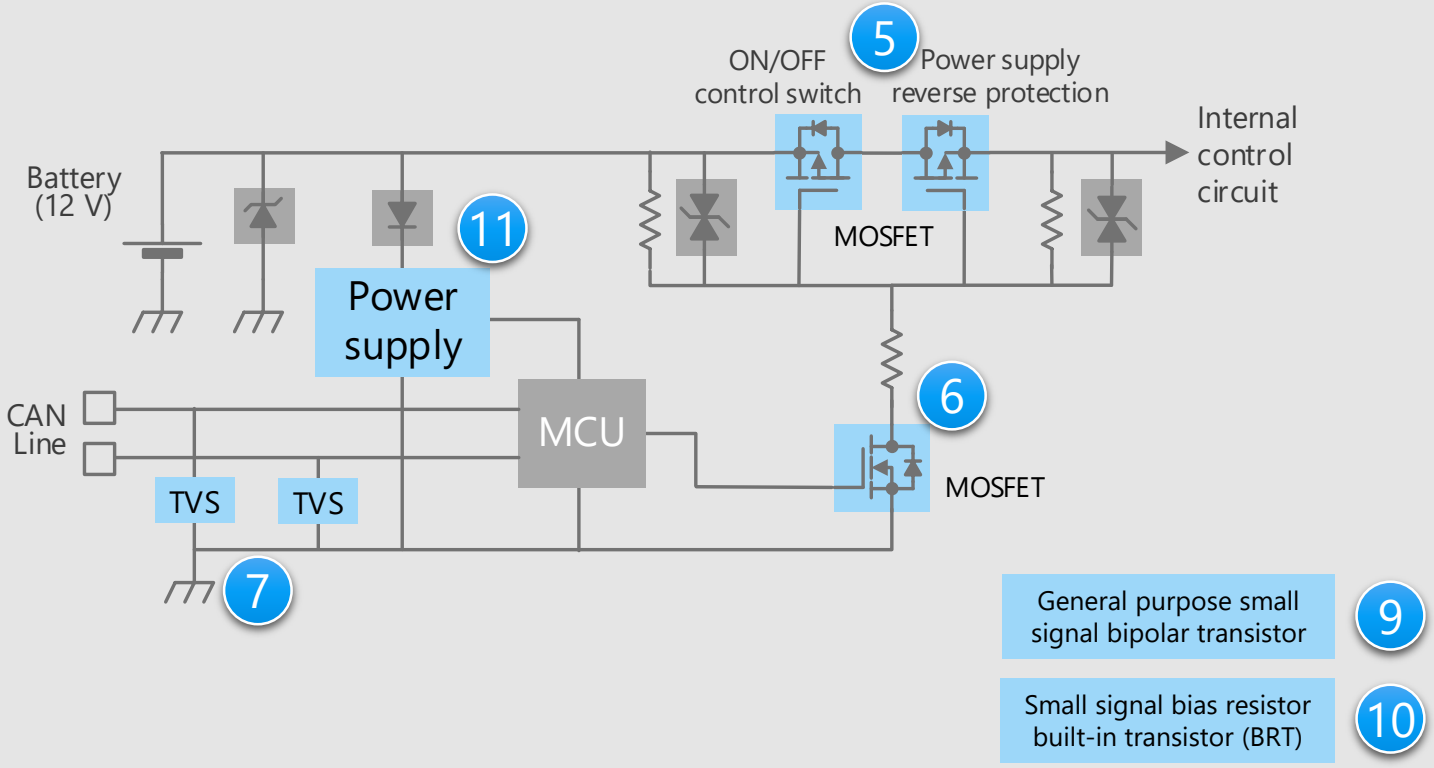
Proposals from Toshiba

- **Low on-resistance contributes low power consumption of the system** 1 5
  U-MOS Series 40 V N-ch MOSFET
  U-MOS Series -40 V / -60 V P-ch MOSFET
- **Gate driver with protection diagnostic function** 3
  Gate driver (for motor)
- **Full bridge pre driver compliant with automotive functional safety standard** 4b 4c 4d
  Brushless DC motor pre driver
- **Voltage regulator with low current consumption** 11
  Power supply IC (for MCU)

Electric Water Pump

Detail of switch for power supply ON/OFF control and reverse connection protection (1)

Power supply ON/OFF control and reverse connection protecting circuit (P-ch type)



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

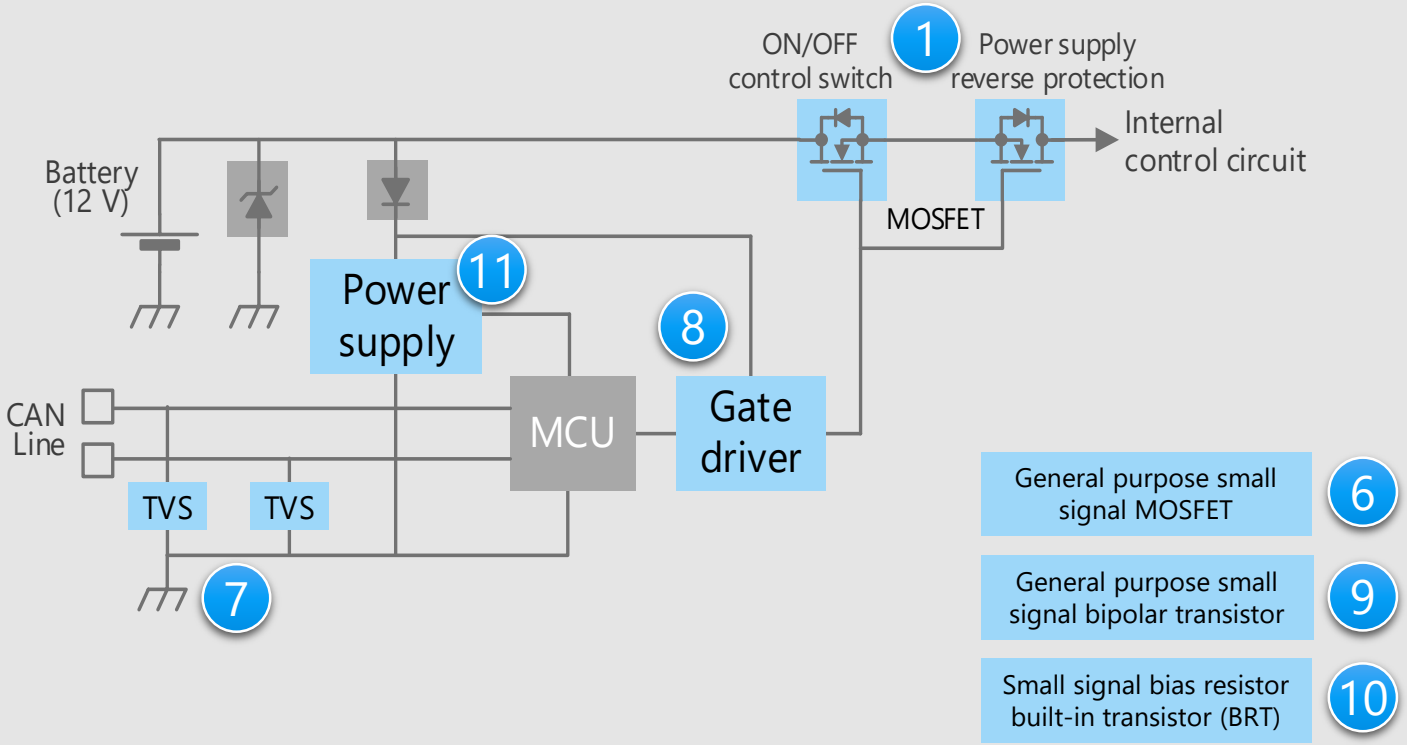
Criteria for device selection

- It is necessary to select the product with the suitable voltage and current ratings for each application.
- It is necessary to select a gate driver according to the characteristics of the switching device to be driven.
- A small surface mount package is suitable for realizing miniaturization of the ECU.

Proposals from Toshiba

- **Low on-resistance contributes low power consumption of the system**
  U-MOS Series -40 V / -60 V P-ch MOSFET 5
- **Extensive product lineup**
  General purpose small signal MOSFET 6
  General purpose small signal bipolar transistor 9
  Small signal bias resistor built-in transistor (BRT) 10
- **Suitable for ESD protection**
  TVS diode (for CAN communication) 7
- **Voltage regulator with low current consumption**
  Power supply IC (for MCU) 11

Power supply ON/OFF control and reverse connection protection circuit (N-ch type)



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

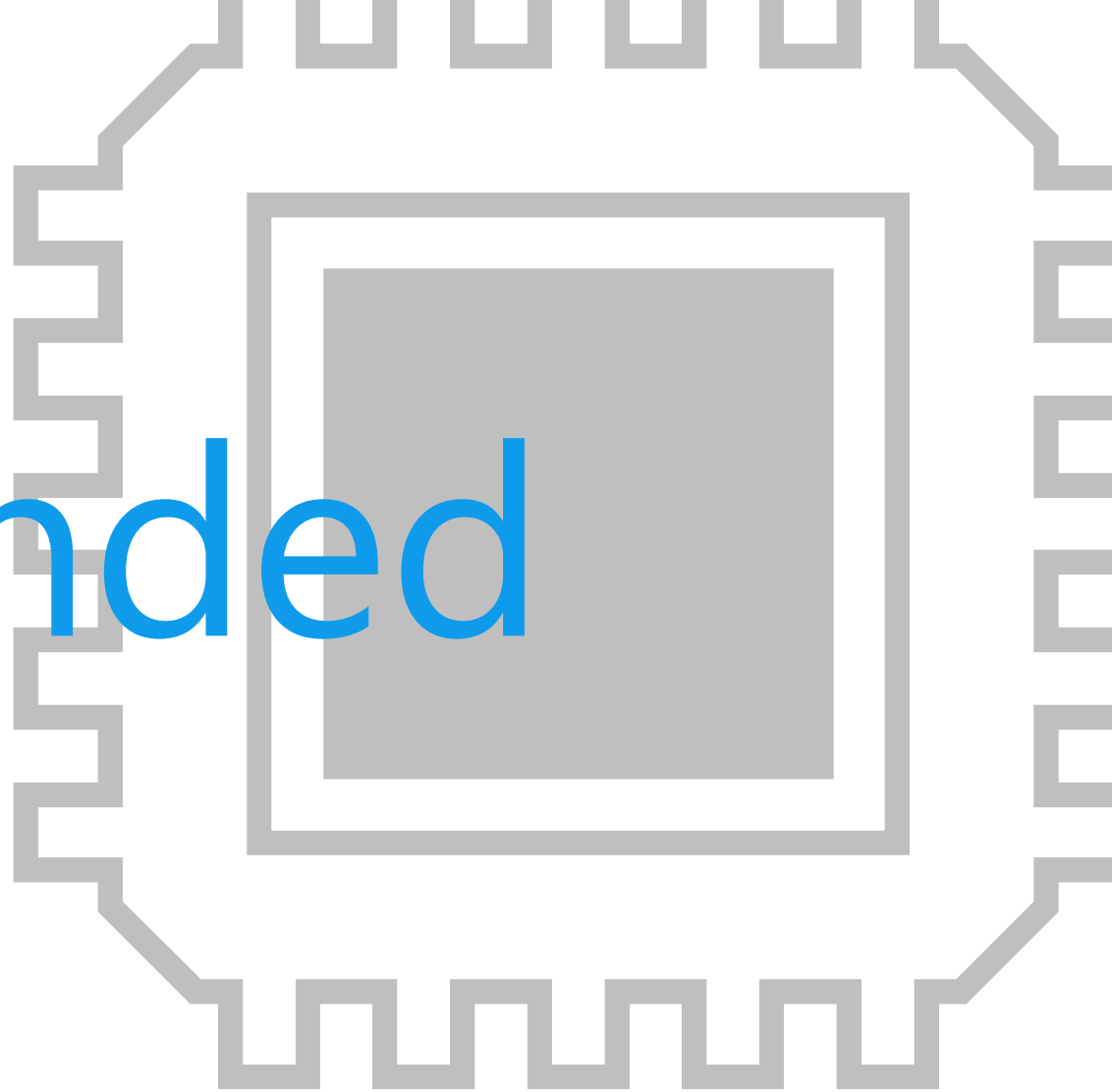
Criteria for device selection

- It is necessary to select the product with the suitable voltage and current ratings for each application.
- It is necessary to select a gate driver according to the characteristics of the switching device to be driven.
- A small surface mount package is suitable for realizing miniaturization of the ECU.

Proposals from Toshiba

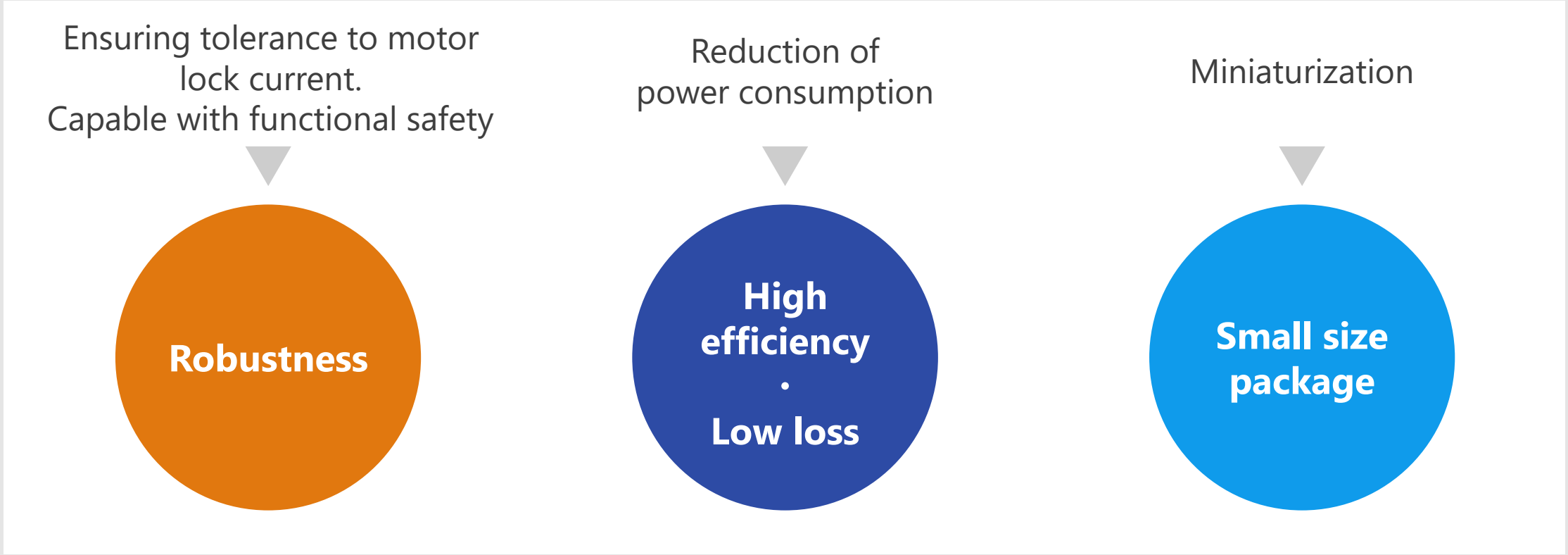
- **Low on-resistance contributes low power consumption of the system**
  U-MOS Series 40 V N-ch MOSFET (1)
- **Gate driver with protection diagnostic function**
  Gate driver (for switch) (8)
- **Extensive product lineup**
  General purpose small signal MOSFET (6)
  General purpose small signal bipolar transistor (9)
  Small signal bias resistor built-in transistor (BRT) (10)
- **Suitable for ESD protection**
  TVS diode (for CAN communication) (7)
- **Voltage regulator with low current consumption**
  Power supply IC (for MCU) (11)

Recommended Devices



Device solutions to address customer needs

As described above, in the design of Electric Water Pump, **“Ensuring tolerance to motor lock current. Capable with functional safety”**, **“Reduction of power consumption”** and **“Miniaturization“** are important factors. Toshiba’s proposals are based on these three solution perspectives.



Device solutions to address customer needs

		Robustness	High efficiency · Low loss	Small size package
1	U-MOS Series 40 V N-ch MOSFET	●	●	●
2	Brushed DC motor pre driver	●	●	
3	Gate driver (for motor)	●		●
4	Brushless DC motor pre driver	●	●	
5	U-MOS Series -40 V / -60 V P-ch MOSFET	●	●	●
6	General purpose small signal MOSFET		●	●
7	TVS diode (for CAN communication)	●		●
8	Gate driver (for switch)	●		●
9	General purpose small signal bipolar transistor			●
10	Small signal bias resistor built-in transistor (BRT)			●
11	Power supply IC (for MCU)		●	●

1 U-MOS Series 40 V N-ch MOSFET

XPN3R804NC / TK1R4S04PB / TPHR7904PB / TPWR7904PB / TKR74F04PB / TK1R5R04PB

Robustness | High efficiency · Low loss | Small size package

Value provided

The advanced U-MOSⅨ-H processes enables low on-resistance and low noise, thereby reducing power consumption.

1 Low loss (reduced on-resistance)

Using low on-resistance technology to contribute to reduced power consumption systems.
On-resistance of 61 % reduction per unit area.
(compared to U-MOSⅣ)

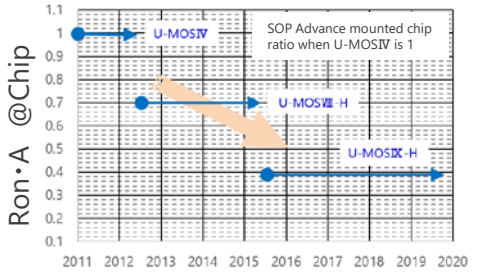
2 Compact and low loss package

By adopting a Cu connector structure and a double-sided heat dissipation structure, low loss and high heat dissipation are realized.
Wettable Frank (WF) package contributes good mountability.

3 Low noise (low EMI)

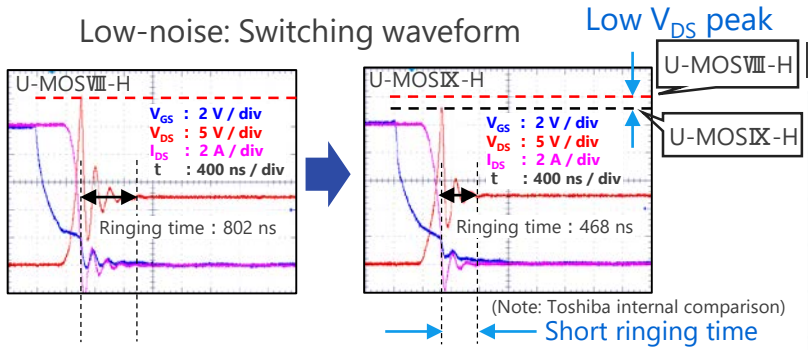
Improved chip process reduces surge voltage and ringing time.

Low Loss: RonA Trend



(Note: Toshiba internal comparison)

Low-noise: Switching waveform

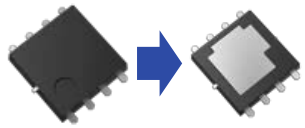


(Note: Toshiba internal comparison)
Short ringing time

TO-220SM(W) Cu connector design

Package resistance is reduced by 64 %, compared to D2PAK+.

DSOP Advance(WF)L double-sided cooling package



Thermal resistance is reduced by 76 % @t = 3 s, mounted on board compared to SOP Advance(WF).

Line up

Part number	Drain current	On-resistance (Max) @V_{GS} = 10 V	Package
XPN3R804NC	40 A	3.8 mΩ	TSON Advance(WF)
TK1R4S04PB	120 A	1.35 mΩ	DPAK+
TPHR7904PB	150 A	0.79 mΩ	SOP Advance(WF)
TPWR7904PB	150 A	0.79 mΩ	DSOP Advance(WF)L
TKR74F04PB	250 A	0.74 mΩ	TO-220SM(W)
TK1R5R04PB	160 A	1.5 mΩ	D2PAK+

◆Return to Block Diagram TOP

2 Brushed DC motor pre driver

TB9057FG

Robustness | High efficiency · Low loss | Small size package

Value provided

Compliant with automotive functional safety standard (ISO26262 : ASIL-D) and motor current detecting function is built in.

1 Compliant with automotive functional safety standard

Compliant with ISO26262 ASIL-D. [Note1] FMEDA [NOTE2] and safety manuals can be provided.

[Note1] Automotive Safety Integrity Level
[Note2] Failure Modes Effects and Diagnostics Analysis

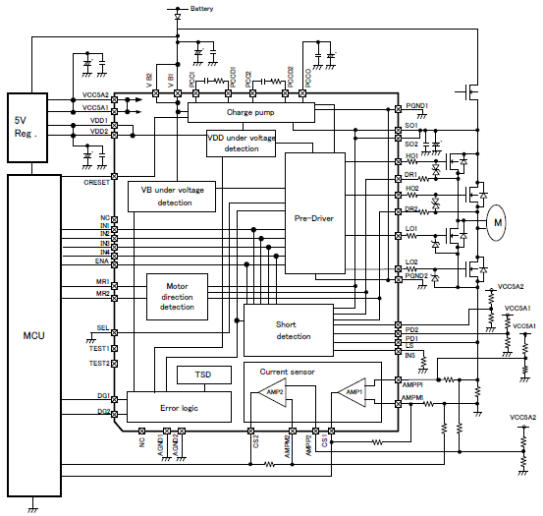
2 Built-in motor current detection amplifier

Two channels of motor current detection amplifiers are built in to make them redundant.

3 AEC-Q100 qualified

It is AEC-Q100 qualified and it can be used for various automotive applications.

TB9057FG Typical Connection Diagram



Line up

Part number		TB9057FG
Package		LQFP48
Package body size		7.0 x 7.0 mm
Function	Control method	Direct
	External MOSFET (High side / Low side)	N-ch / N-ch
	Detection of overheating, low voltage and short circuit	✓
	Output of detection function diagnosis result	✓

◆Return to Block Diagram TOP

3 Gate driver (for motor)

TPD7211F / TPD7212F / TPD7212FN

Robustness | High efficiency · Low loss | Small size package

Value provided

The high gate drive current capability reduces MOSFET losses and improves the efficiency of system.

1 High gate drive current

High drive current capability and high speed switching contribute to reduce the loss.

- TPD7211F: ±0.5 A
- TPD7212F, TPD7212FN: -1 / +1.5 A

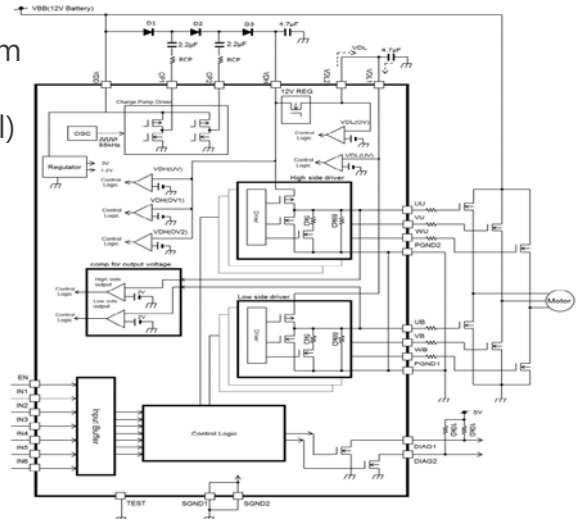
2 Built-in protection / diagnostic output function

MOSFET is turn off when a signal is input that causes arm short circuit.
Functions to monitor abnormalities of the power supply voltage and output voltage are built-in.

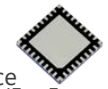
3 Small surface mount package

PS-8, WQFN32 and SSOP30 are small surface mount packages. It contributes to the miniaturization of system.

Example of application and block diagram of TPD7212F, TPD7212FN
(Three phase brushless DC motor control)



Line up

Part number	TPD7211F	TPD7212F / TPD7212FN
Function	Half bridge output gate driver	Gate driver for three-phase brushless motor
Number of output	2 outputs	6 outputs
Package	 PS-8 (2.8 x 2.9 mm)	TPD7212F  Back surface WQFN32 (5 x 5 mm) TPD7212FN  SSOP30 (7.6 x 10.2 mm)
Features	・For high-side P-ch MOSFET drive	・For driving high-side N-ch MOSFET (with built-in charge pumps) ・Built-in voltage monitoring function (power supply, output)

◆Return to Block Diagram TOP

4a Brushless DC motor pre driver

TB9081FG / TB9083FTG*

Robustness | High efficiency · Low loss | Small size package

Value provided

Compliant with automotive functional safety standard (ISO 26262 : ASIL-D) and safety relay drivers are built in.

1 Compliant with automotive functional safety standard

Compliant with ISO 26262 ASIL-D. [NOTE 1] FMEDA [NOTE 2] and safety manuals can be provided.

[NOTE 1] Automotive Safety Integrity Level
[NOTE 2] Failure Modes Effects and Diagnostics Analysis

2 Built-in safety relay drivers and motor current detection amplifiers

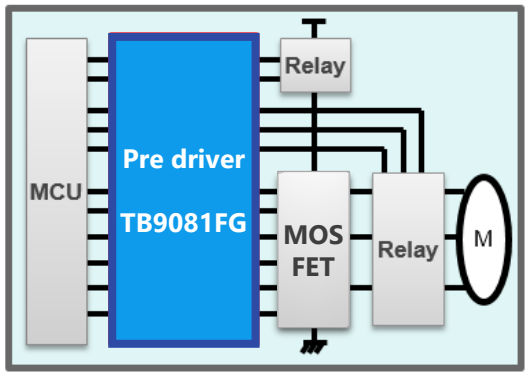
The safety relay drivers are built in for the power supply side MOSFETs and the motor phase cut MOSFETs. In addition, a 3 channels of motor current detection amplifiers are built in to support 3 shunts.

3 AEC-Q100 qualified

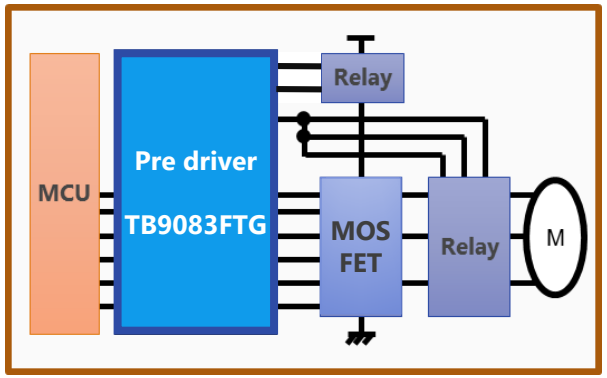
It is AEC-Q100 qualified and it can be used for various automotive applications.

Built-in safety relay drivers

TB9081FG : 5 channels



TB9083FTG : 3 channels



Line up

Part number		TB9081FG	TB9083FTG*
Package		LQFP64	WQFN48
Package body size		10.0 x 10.0 mm	7.0 x 7.0 mm
Operating ambient temperature		Ta = -40 to 125 °C	Ta = -40 to 150 °C
Function	Control method	Direct	Direct
	External MOSFET (High side / Low side)	N-ch / N-ch	N-ch / N-ch
	Detection of overheating, low voltage and short circuit	✓	✓
	Output of detection function diagnosis result	✓ (BIST [Note 3])	✓ (BIST)

[Note 3] Built-in Self Test

◆Return to Block Diagram TOP

* TB9083FTG: Under development (The specification is subject to change without notice.)

Brushless DC motor pre driver

TB9061AFNG

Robustness | High efficiency · Low loss | Small size package

Value provided

It is built in a sensorless control circuit and can drive a brushless DC motor without using Hall elements.

1 Three-phase sensorless drive

It can drive a brushless DC motor by change of detecting the back electromotive force of each motor phase without using Hall elements.

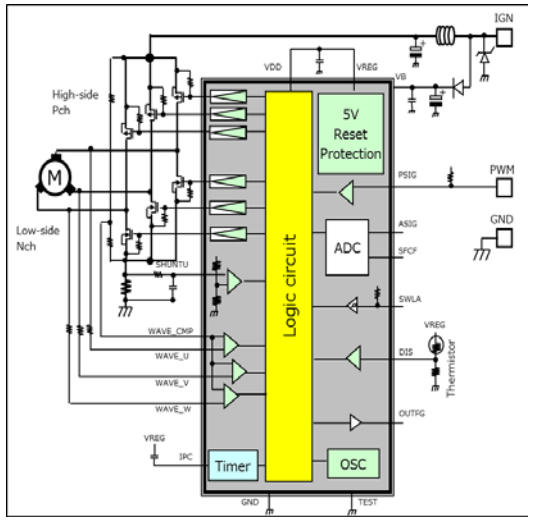
2 Built-in external MOSFET drive circuits

It is built in 6 drivers for external P-ch and N-ch MOSFETs.

3 AEC-Q100 qualified

AEC-Q101 qualified and can be used for various automotive applications.

Application circuit example



Line up

Part number	TB9061AFNG
Package	SSOP24 (7.8 x 7.6 mm)
Power supply voltage VB (Max) [V]	40
Output voltage VOH / VOL [V]	VB-0.5@ IOH = -20 mA / 0.5 @ IOL = 20 mA
PWM frequency fpint (Typ.) [kHz]	24
Oscillation frequency fosc (Typ.) [MHz]	6.14

◆Return to Block Diagram TOP

Brushless DC motor pre driver

TB9062FNG

Robustness | High efficiency · Low loss | Small size package

Value provided

Sensorless control circuit is built in and can be used without Hall devices.

1 3-phase sensorless drive system

Brushless DC motor can be driven without Hall devices by detecting changes in the induced voltage of each phase of the motor.

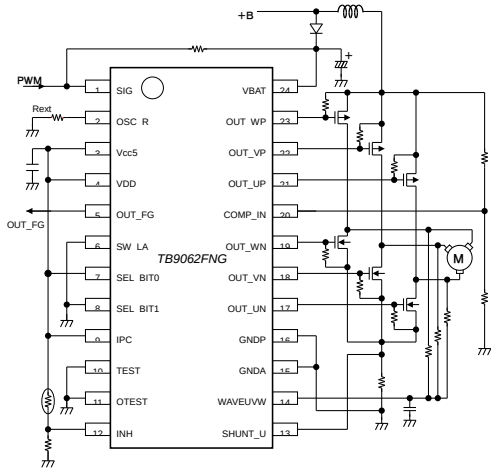
2 3-phase 6 outputs for external MOSFETs driving

It has 3-phase 6 outputs for P-channel / N-channel external MOSFETs driving.

3 Stable start-up and step-out prevention function

Stable start-up is realized because the start duty is automatically selected according to the battery voltage fluctuation. It also has a function to suppress the sudden change in output duty in response to a sudden change in input duty to prevent step-out.

Application circuit example



Line up

Part number	TB9062FNG
Package	SSOP24-P-300-0.65A (7.8 x 7.6 mm) 
Power supply voltage V_B [V] (Max)	40
Output voltage V_{OH} / V_{OL} [V] (Max)	V_B-0.5 / 0.5 @ I_{OUT}=1 mA
PWM frequency f_{pint} [kHz] (Typ.)	17.0 @ Rext=39 kΩ
Oscillation frequency f_{osc} [MHz] (Typ.)	4.00 @ Rext=39 kΩ

◆Return to Block Diagram TOP

Brushless DC motor pre driver

TB9067FNG

Robustness | High efficiency ・ Low loss | Small size package

Value provided

It is suitable for sensor type brushless DC motor control.

1 Compatible with both internal PWM drive and external direct drive

The PWM signals can be input are as follows.

PWM frequency

- Internal PWM drive : 4 kHz (Max)
- External direct drive : 23 kHz (Max)

2 3-phase 6 outputs for external MOSFETs driving

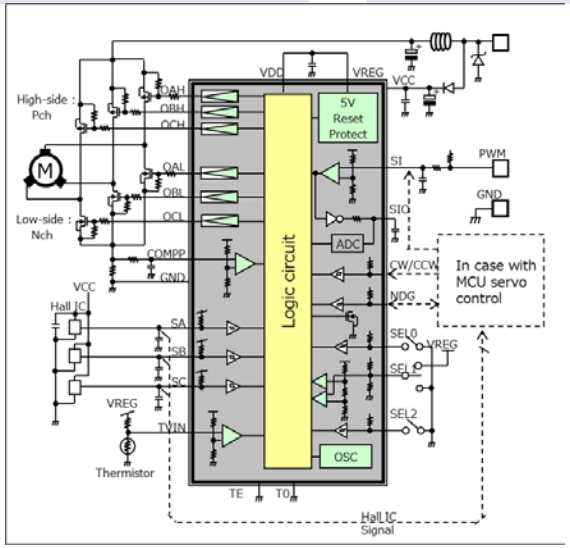
It has 3-phase 6 outputs for P-channel / N-channel external MOSFETs driving.

3 Built-in various abnormality detection functions

This IC has a variety of built-in abnormality detection functions.

- External motor driver overcurrent / overheat detection
- BIAS voltage rise / fall detection
- 100 % drive detection

Application circuit example



Line up

Part number	TB9067FNG
Package	SSOP24-P-300-0.65A (7.8 x 7.6 mm) 
Power supply voltage V_B [V] (Max)	40
Output voltage V_{OH} (Min) / V_{OL} (Max) [V]	BIAS-0.3 / 0.3 @ I_{OUT}=∓10 mA
PWM frequency f_{pint} [kHz] (Typ.)	20
Oscillation frequency f_{osc} [MHz] (Typ.)	5.12

◆Return to Block Diagram TOP

5 U-MOS Series -40 V / -60 V P-ch MOSFET

TJ90S04M3L / TJ60S06M3L / XPH3R114MC / TJ200F04M3L

Robustness | High efficiency · Low loss | Small size package

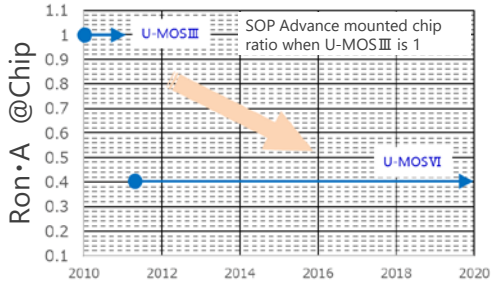
Value provided

Low on-resistance contributes to reduce system power consumption.

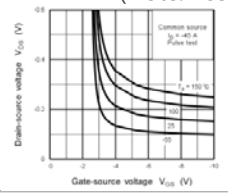
1 Low loss (reduced on-resistance) and logic level drive

Using low on-resistance technology contributes to reduce system power consumption.
Lineups of logic level drive type are supported.

Low Loss: RonA Reduction Trend



(Note: Toshiba internal comparison)



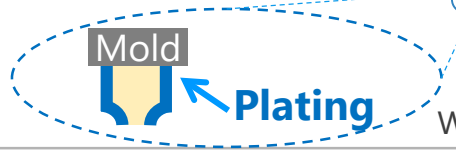
Logic level drive
$V_{DS(ON)}$ - V_{GS}

Large current, small size, high heat dissipation package

TO-220SM(W)
(10 x 13 mm)
Up to 200 A

DPAK+
(6.5 x 9.5 mm)
Up to 90 A

SOP Advance(WF)
(5 x 6 mm)
Up to 100 A



Wettable Flank (WF) structure

2 Small surface mount package developed

By adopting a Cu connector structure and a double-sided heat dissipation structure, low loss and high heat dissipation are realized.
Wettable Frank (WF) package contributes good mountability.

Line up

Part number	Drain-source Voltage	Drain current	On-resistance (Max) @V_{GS} = -10 V	Package
TJ90S04M3L	-40 V	-90 A	4.3 mΩ	DPAK+ 
TJ60S06M3L	-60 V	-60 A	11.2 mΩ	
XPH3R114MC	-40 V	-100 A	3.1 mΩ	SOP Advance(WF) 
TJ200F04M3L	-40 V	-200 A	1.8 mΩ	TO-220SM(W) 

◆Return to Block Diagram TOP

6 General purpose small signal MOSFET

SSM3K7002KF / SSM3J168F / SSM3J66MFV

Robustness | High efficiency · Low loss | Small size package

Value provided

Wide lineup of small packages contribute to reduce the size and power consumption of system.

1 Small package

A lineup of various small packages such as SOT-723 (VESM 1.2 x 1.2 mm package) is available, contributing to reduce mounting area.

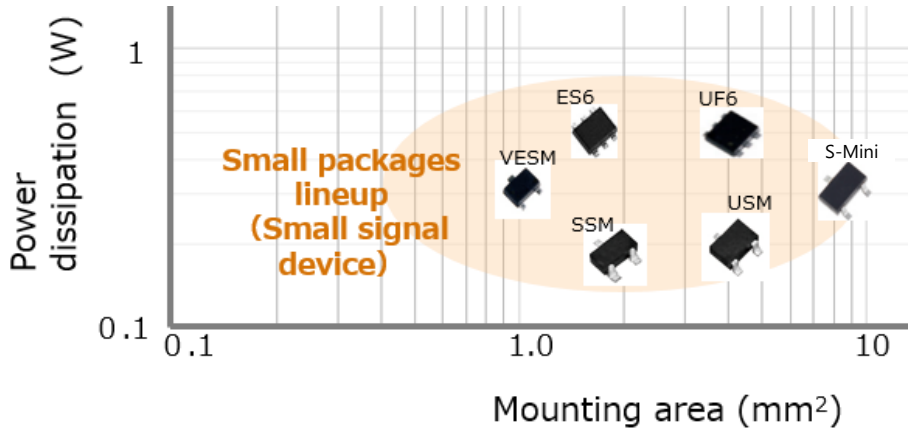
2 Low voltage drive

SSM3J66MFV can be driven at low gate-source voltage of 1.2 V.

3 AEC-Q101 qualified

AEC-Q101 qualified and can be used for various automotive applications.

Small signal package lineup



Line up

Part number		SSM3K7002KF	SSM3J168F	SSM3J66MFV
Package		S-Mini (SOT-346)	S-Mini (SOT-346)	VESM (SOT-723)
V_{DSS} [V]		60	-60	-20
I_D [A]		0.4	-0.4	-0.8
$R_{DS(ON)}$ @$\|V_{GS}\|$=4.5 V [Ω]	Typ.	1.2	1.4	0.31
	Max	1.75	1.9	0.39
Drive voltage [V]		4.5	-4.0	-1.2
Polarity		N-ch	P-ch	P-ch

◆Return to Block Diagram TOP

7 TVS diode (for CAN communication)

DF3D18FU / DF3D29FU / DF3D36FU

Robustness | High efficiency · Low loss | Small size package

Value provided

TVS diodes prevent system damage and malfunction caused by electrostatic discharge (ESD).

1 Improve ESD pulse absorbability

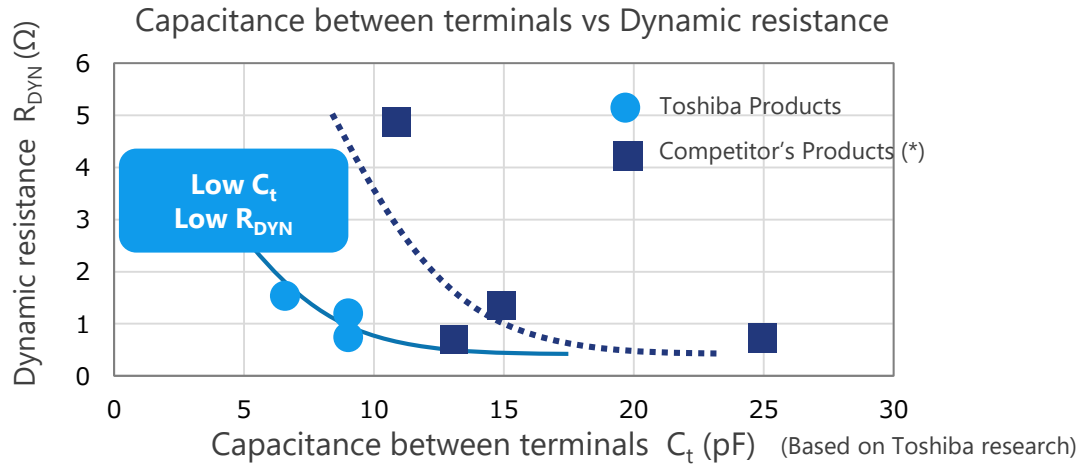
Toshiba proprietary Zener process improves the ESD pulse absorption of TVS diodes.
(Both low dynamic resistance R_{DYN} and low capacitance between terminals C_t)

2 Supports CAN, CAN FD and FlexRay

These are products applicable to in-vehicle LAN communication such as CAN, CAN FD and FlexRay.

3 High ESD immunity

V_{ESD} > ±30 kV @ ISO 10605
V_{ESD} > ±20 kV (L4) @ IEC61000-4-2



(Based on Toshiba research)

(NOTE) : This product is an ESD protection diode and cannot be used for purposes other than ESD protection.

(*): Measurements of the commercial product

Line up

Part number	DF3D18FU	DF3D29FU	DF3D36FU
Package	USM (SOT-323) 		
V_{ESD} [kV] @ISO 10605	±30	±30	±20
V_{RWM} (Max) [V]	12	24	28
C_t (Typ. / Max) [pF]	9 / 10		6.5 / 8
R_{DYN} (Typ.) [Ω]	0.8	1.1	1.5

◆Return to Block Diagram TOP

8 Gate driver (for switch)

TPD7104AF / TPD7106F / TPD7107F

Robustness | High efficiency · Low loss | Small size package

Value provided

A charge pump circuit for the N-ch MOSFET gate drive is built in, allowing for easy semiconductor relay configuration.

1 Built-in charge pump circuit

Built-in charge pump circuit enables N-ch MOSFET as high side switch.
Easy to configure a semiconductor relay.

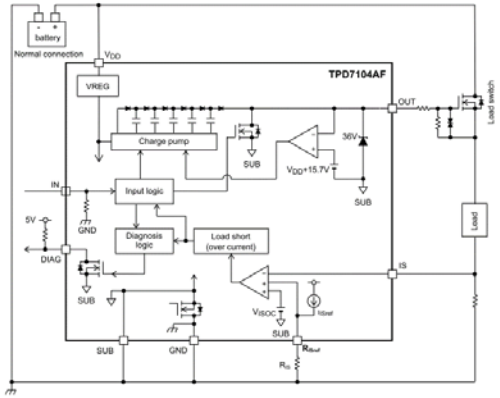
2 Can be controlled by logic level voltage

It is possible that Direct control by output signal of MCUs or CMOS logic ICs.

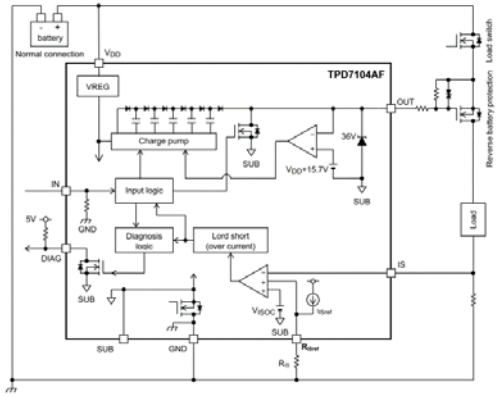
3 Small package

The small surface mount packages such as PS-8, SSOP16 and WSON10A contribute to the miniaturization of equipment.

Semiconductor relay (switch) application (TPD7104AF)



Power supply reverse connection protection MOSFET control (TPD7104AF)



Back to back configuration

Line up

Part number	TPD7104AF	TPD7106F	TPD7107F
Package	PS-8 (2.8 x 2.9 mm)	SSOP16 (5.5 x 6.4 mm)	WSON10A (3 x 3 mm)
Features	・Operating power supply voltage range: 5 to 18 V ・Built-in power supply reverse connection protection function (Supported for power supply reverse connection protection MOSFET applications)	・Operating power supply voltage range: 4.5 to 27 V ・Built-in power supply reverse connection protection function (Supported for power supply reverse connection protection MOSFET applications)	・Operating power supply voltage range: 5.75 to 26 V ・Current sense output ・Protective functions; overcurrent, overtemperature, GND disconnect etc. reverse battery connection ・Diagnosis output; overcurrent, load open, overtemperature etc.

◆Return to Block Diagram TOP

9 General purpose small signal bipolar transistor

2SC2712 / 2SA1162 / 2SC4116 / 2SA1586 / TTA501 / TTC501 and others

Robustness | High efficiency · Low loss | Small size package

Value provided

Extensive product lineup to meet customers' needs.

1 Extensive lineup of packages

Various packages such as 1-in-1, 2-in-1 are provided and suitable products for circuit board design are selectable.

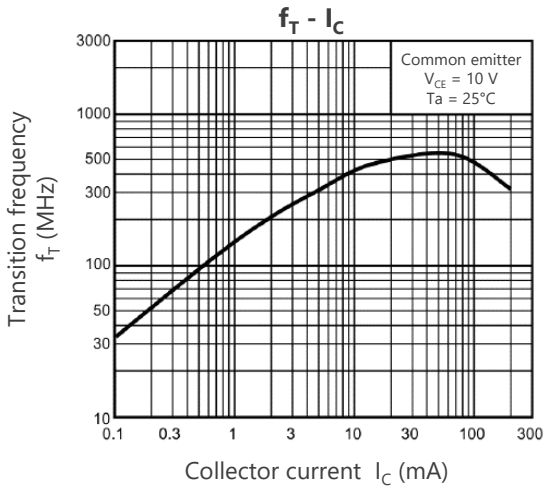
2 Extensive product lineup

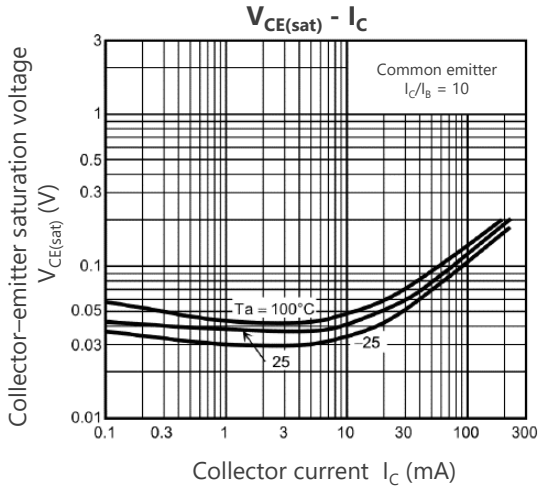
Various product lineups, such as general purpose, low noise, low $V_{CE(sat)}$ and high current types are provided. Products can be selected in accordance to the application.

3 AEC-Q101 qualified

AEC-Q101 qualified and can be used for various automotive applications.

Characteristic examples of 2SC2712





Line up

Package			SOT-23F		USM (SOT-323) UFM (SOT-323F)*		S-Mini (SOT-346)	
Classification	$\|V_{CEO}\|$ [V]	$\|I_C\|$ [mA]	NPN	PNP	NPN	PNP	NPN	PNP
General purpose	50	150			2SC4116	2SA1586	2SC2712	2SA1162
	50	500					2SC3325	2SA1313
Low noise	120	100			2SC4117	2SA1587	2SC2713	2SA1163
High current	50	1700				2SA2195*		
	50	2000		TTA501				
	100	2500	TTC501					

◆Return to Block Diagram TOP

10 Small signal bias resistor built-in transistor (BRT)

RN1907FE / RN2907FE / RN1901 / RN2901 Series

Robustness | High efficiency · Low loss | Small size package

Value provided

Extensive product lineup to meet customers' needs.

1 Built-in bias resistor type
(BRT : Bias Resistor built-in Transistor)

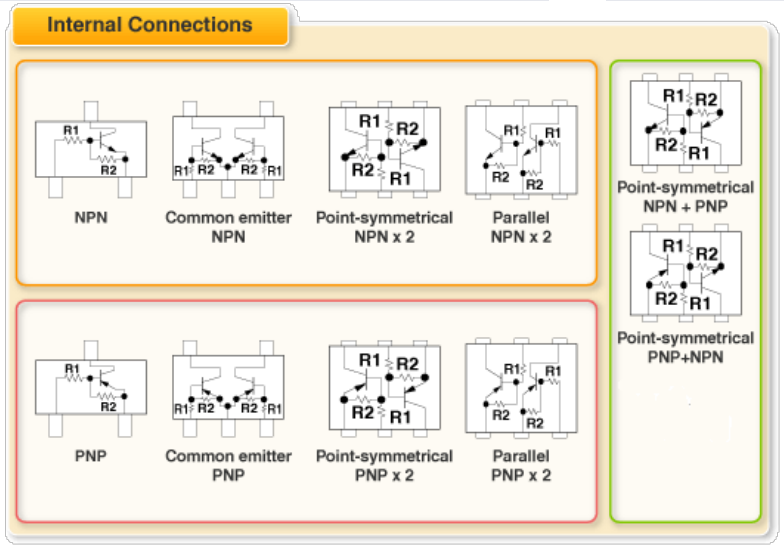
The BRTs contribute to reduction of the number of components, assembly workload and mounting area of circuit boards.

2 Extensive lineup of package and pin assignment

Various package lineups, such as 1-in-1, 2-in-1 and various pin assignment type are provided and suitable products for circuit board design are selectable.

3 AEC-Q101 qualified

AEC-Q101 qualified and can be used for various automotive applications.



Line up

Part number		NPN (BRT)	PNP (BRT)
Package	ES6 (SOT-563)	RN1907FE	RN2907FE
	US6 (SOT-363)	RN1901	RN2901
V_{CEO} (Max) [V]		50	-50
I_C [mA]		100	-100

◆Return to Block Diagram TOP

11 Power supply IC (for MCU)

TB9005FNG

Robustness | High efficiency · Low loss | Small size package

Value provided

This is voltage regulator with low current consumption, and various monitoring functions such as WDT[Note] contribute to improving system stability.

[Note]: Watchdog Timer

1 Low current consumption

External transistor type voltage regulator with low current consumption.
Load stability is +/-1 %.

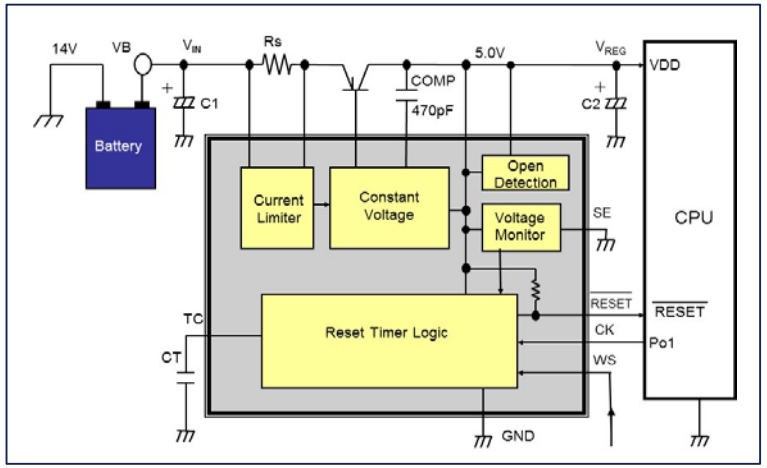
2 Built-in WDT and various monitoring functions

The WDT monitors the operation of the MCU.
In addition, current detection functions contribute to improving system safety.

3 AEC-Q100 qualified

It is AEC-Q100 qualified and can be used for various automotive applications.

Application circuit example (The current limiter can be adjusted by an external resistor.)



Line up

Part number		TB9005FNG
Package		SSOP20 (6.4 x 7.0 mm
Current consumption I_{CC} (Typ.) [µA]		90 (@V_{IN} = 12 V, Ta = 25 °C)
Load stability VLOAD (Max) [%]		1 (@ILOAD = 1 to 300 mA)
Function	Number of outputs	1 ch (5 V)
	Circuit type	External transistor type
	WDT, Overcurrent limitation	✓

◆Return to Block Diagram TOP

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